

# HFA16TB120S

HEXFRED™

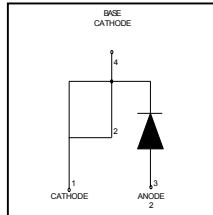
Ultrafast, Soft Recovery Diode

## Features

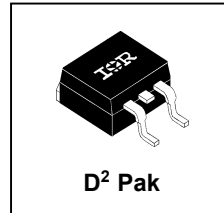
- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low  $I_{RRM}$
- Very Low  $Q_{rr}$
- Specified at Operating Conditions

## Benefits

- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count



$V_R = 1200V$
$V_F(\text{typ.})^* = 2.3V$
$I_F(\text{AV}) = 16A$
$Q_{rr}(\text{typ.}) = 260nC$
$I_{RRM}(\text{typ.}) = 5.8A$
$t_{rr}(\text{typ.}) = 30ns$
$di_{(rec)}/dt(\text{typ.})^* = 76A/\mu s$



## Description

International Rectifier's HFA16TB120S is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 volts and 16 amps continuous current, the HFA16TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current ( $I_{RRM}$ ) and does not exhibit any tendency to "snap-off" during the  $t_b$  portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA16TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

## Absolute Maximum Ratings

	Parameter	Max	Units
$V_R$	Cathode-to-Anode Voltage	1200	V
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	16	A
$I_{FSM}$	Single Pulse Forward Current	190	
$I_{FRM}$	Maximum Repetitive Forward Current	64	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	151	°C
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	60	
$T_J$	Operating Junction and	-55 to +150	W
$T_{STG}$	Storage Temperature Range		

\* 125°C

**Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

	Parameter	Min	Typ	Max	Units	Test Conditions
V <sub>BR</sub>	Cathode Anode Breakdown Voltage	1200			V	I <sub>R</sub> = 100μA
V <sub>FM</sub>	Max Forward Voltage		2.5	3.0	V	I <sub>F</sub> = 16A
			3.2	3.93		I <sub>F</sub> = 32A See Fig. 1
			2.3	2.7		I <sub>F</sub> = 16A, T <sub>J</sub> = 125°C
I <sub>RM</sub>	Max Reverse Leakage Current		0.75	20	μA	V <sub>R</sub> = V <sub>R</sub> Rated See Fig. 2
			375	2000		T <sub>J</sub> = 125°C, V <sub>R</sub> = 0.8 x V <sub>R</sub> Rated
C <sub>T</sub>	Junction Capacitance		27	40	pF	V <sub>R</sub> = 200V See Fig. 3
L <sub>S</sub>	Series Inductance		8.0		nH	Measured lead to lead 5mm from package body

**Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

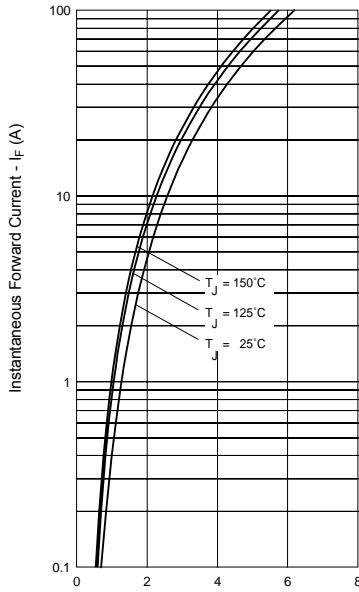
	Parameter	Min	Typ	Max	Units	Test Conditions
t <sub>rr</sub>	Reverse Recovery Time		30		ns	I <sub>F</sub> = 1.0A, di/dt = 200A/μs, V <sub>R</sub> = 30V
t <sub>rr1</sub>	See Fig. 5, 10		90	135		T <sub>J</sub> = 25°C
			164	245		T <sub>J</sub> = 125°C
I <sub>RRM1</sub>	Peak Recovery Current		5.8	10	A	T <sub>J</sub> = 25°C
			8.3	15		T <sub>J</sub> = 125°C
I <sub>RRM2</sub>	See Fig. 6					V <sub>R</sub> = 200V
Q <sub>rr1</sub>	Reverse Recovery Charge		260	675	nC	T <sub>J</sub> = 25°C
Q <sub>rr2</sub>	See Fig. 7		680	1838		T <sub>J</sub> = 125°C
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current		120		A/μs	T <sub>J</sub> = 25°C
			76			T <sub>J</sub> = 125°C
di <sub>(rec)M</sub> /dt2	During t <sub>b</sub> See Fig. 8					di/dt = 200A/μs

**Thermal - Mechanical Characteristics**

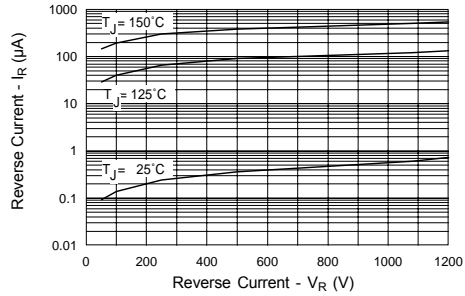
	Parameter	Min	Typ	Max	Units
T <sub>lead</sub> ①	Lead Temperature			300	°C
R <sub>thJC</sub>	Thermal Resistance, Junction to Case			0.83	K/W
R <sub>thJA</sub> ②	Thermal Resistance, Junction to Ambient			80	
Wt	Weight		2.0		g
			0.07		(oz)

① 0.063 in. from Case (1.6mm) for 10 sec

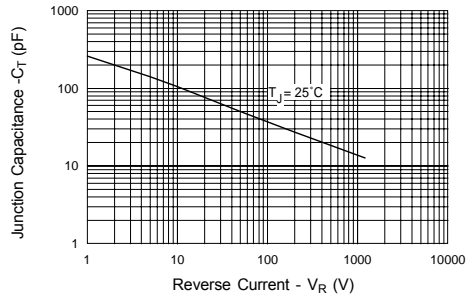
② Typical Socket Mount



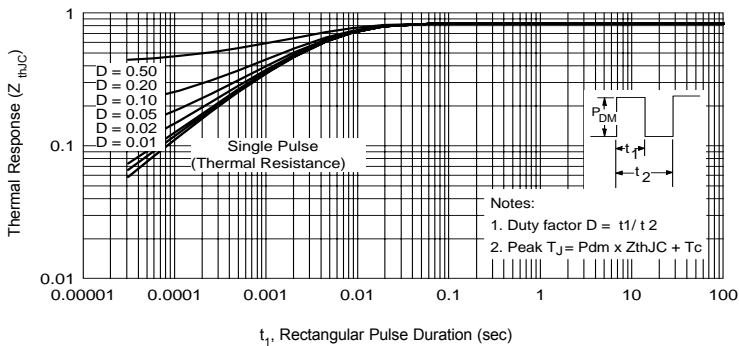
**Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current**



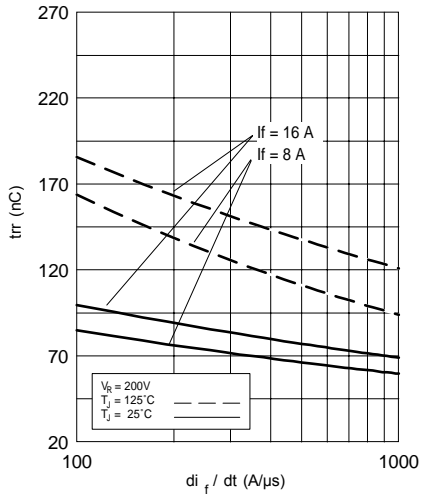
**Fig. 2 - Typical Reverse Current vs. Reverse Voltage**



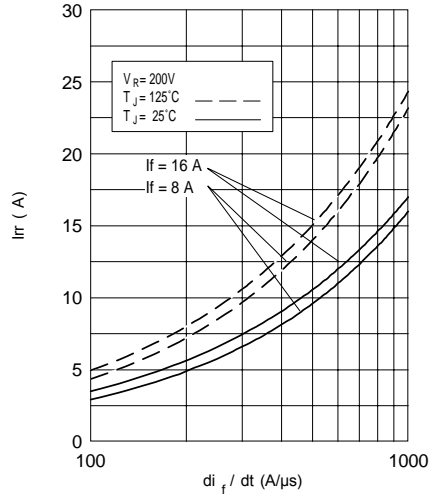
**Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage**



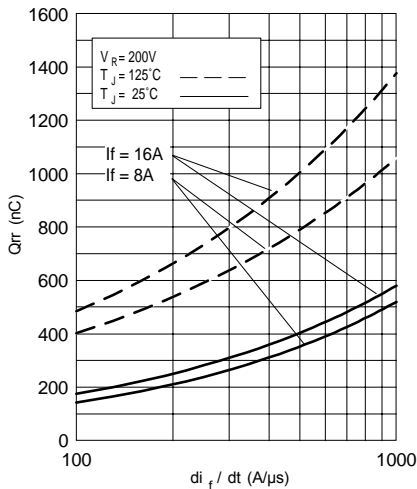
**Fig. 4 - Maximum Thermal Impedance  $Z_{th(jc)}$  Characteristics**



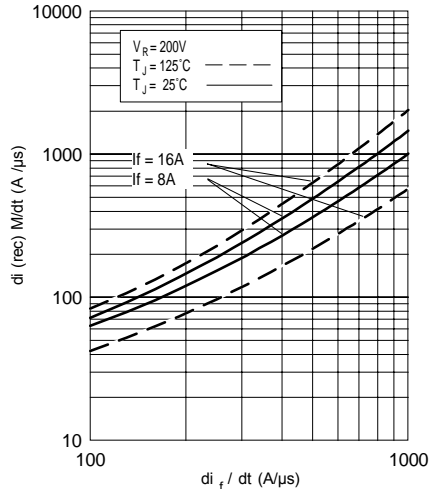
**Fig. 5 - Typical Reverse Recovery vs.  $d i_f / dt$ , (per Leg)**



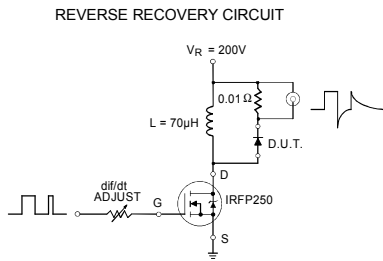
**Fig. 6 - Typical Recovery Current vs.  $d i_f / dt$ , (per Leg)**



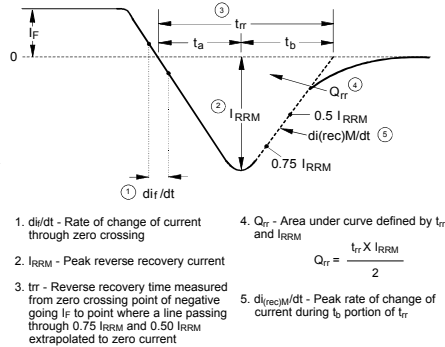
**Fig. 7 - Typical Stored Charge vs.  $d i_f / dt$ , (per Leg)**



**Fig. 8 - Typical  $d i_{(rec)} M / dt$  vs.  $d i_f / dt$ , (per Leg)**



**Fig. 9 - Reverse Recovery Parameter Test Circuit**



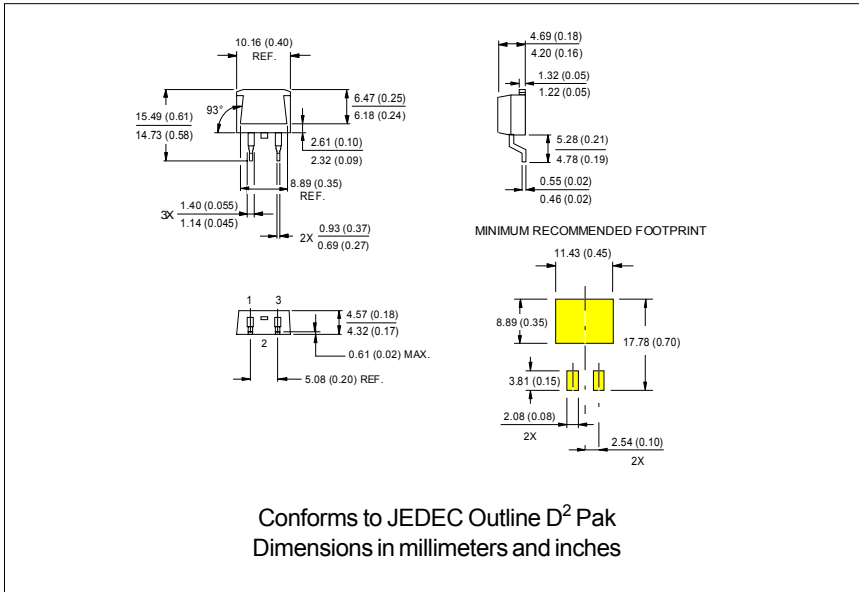
**Fig. 10 - Reverse Recovery Waveform and Definitions**

# HFA16TB120S

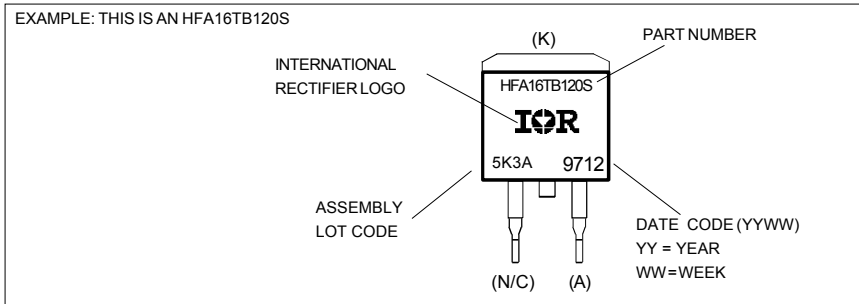
Bulletin PD-20605 rev. B 11/00



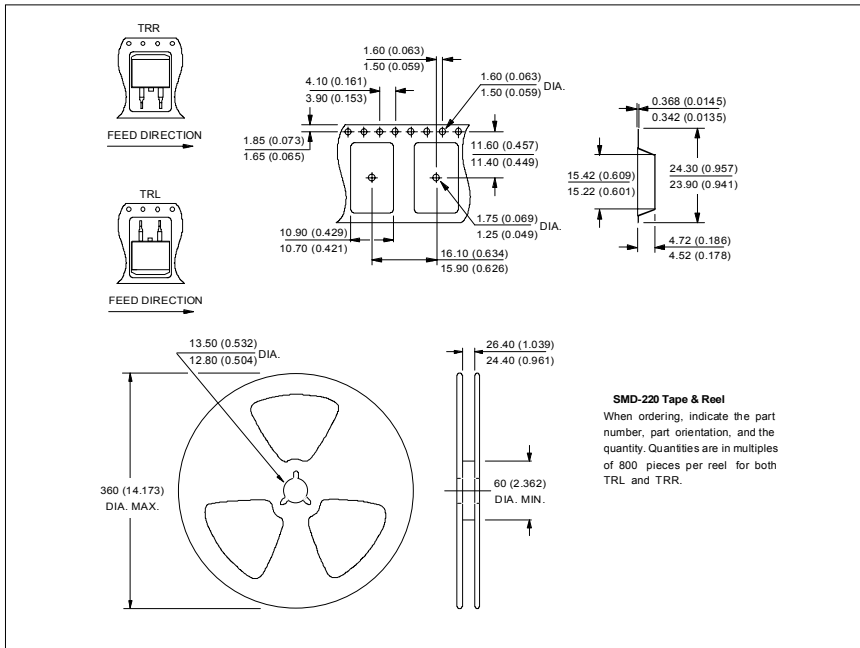
## Outline Table



## Part Marking Information



**Tape & Reel Information**



**WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.  
**EUROPEAN HEADQUARTERS:** Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408.  
**IR CANADA:** 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.  
**IR GERMANY:** Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933.  
**IR ITALY:** Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.  
**IR FAR EAST:** K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.  
**IR SOUTHEAST ASIA:** 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.  
**IR TAIWAN:** 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

<http://www.irf.com>

Fax-On-Demand: +44 1883 733420

Data and specifications subject to change without notice.